IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: : Date: July 22, 2003

Leo Mathew et al. : Attorney Docket No.: SC12862TC

Serial No.: : Art Unit:

Filing Date: : Examiner: Unassigned

For: METHOD FOR CONVERTING A PLANAR TRANSISTOR DESIGN TO A

VERTICAL DOUBLE GATE TRANSISTOR DESIGN

INFORMATION DISCLOSURE STATEMENT (IDS)

Commissioner For Patents P.O. Box 1450 Alexandria, VA 22313-1450

SIR:

In accordance with 37 C.F.R. §1.56 and in compliance with 37 C.F.R. §§1.97 and 1.98, the references listed on attached Form PTO/SB/08 and/or subsequently identified herein, are being submitted herewith for consideration by the United States Patent and Trademark Office.

I. <u>COPIES</u>

- a. A legible copy of (i) each U.S. and foreign patents; (ii) each publication or that portion which caused it to be listed; and (iii) all other information or that portion which caused it to be listed, is included herewith.
- b. Any patents, publications or other information which are listed on PTO/SB/08 which are not enclosed herewith were previously cited by or submitted to the PTO in one of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. §120:

U.S. Serial Number

U.S. Filing Date

II. <u>CONCISE EXPLANATION OF THE RELEVANCE</u> (check at least one box)

a. Except as may be indicated below in (b) of this section, all of the patents, publications or other information are in the English language (concise explanation not required).

	b. 🗌	A concise explanation of the relevance of all patents, publications or other information listed that is not in the English language is as follows: The following additional information is provided for the Examiner's consideration:
ш. 🗀	The E	S REFERENCE TO RELATED APPLICATION(S) xaminer is advised that the following co-pending application(s) contain(s) subject that may be related to the present application. By bringing this (these) applications Examiner's attention, Applicant(s) does(do) not waive the confidentiality ions of 35 U.S.C. §122.
	<u>Serial</u> 10/074	
		<u>FEES</u>
IV. 🔀	THIS I	DS IS BEING FILED UNDER 37 C.F.R. §1.97(b): (check one box) within three months of the filing date of a national application other than a
		continued prosecution application under § 1.53(d) (37 C.F.R. §1.97(b)(1)). No
		fee or statement is required.
	b. 🗌	within three months of the date of entry of the national stage as set forth in §
		1.491 in an international application (37 C.F.R. §1.97(b)(2)). No fee or statement
		is required.
	c	before the mailing date of a first Office Action on the merits (37 C.F.R.
		§1.97(b)(3)). No fee or statement is required.
	d.	before the mailing date of a first Office Action after the filing of a request for
		continued examination under § 1.114 (37 C.F.R. § 1.97(b)(4)). No fee or
		statement is required.
V. 🔲	THIS I	DS IS BEING FILED UNDER 37 C.F.R. §1.97(c): (check one box)
	before	the mailing date of either a Final Office Action under 37 C.F.R. §1.113 (See 37
	C.F.R.	§1.97(c)), or a Notice of Allowance under 37 C.F.R. §1.311 (See 37 C.F.R.
	§1.97(d	
	a. 🗌	No statement; therefore, charge deposit account 502117 the fee set forth in 37 C.F.R. §1.17(p).
	b. 🗌	See the statement below. No fee is required.
VI. 🗌	THIS I	DS IS BEING FILED UNDER 37 C.F.R. §1.97(d):
	on or b	efore payment of the issue fee and is accompanied by the following:

- 1) a statement under 37 C.F.R. §1.97(e) as provided below;
- Applicant(s) hereby a petition for consideration of this information disclosure statement; and
- 3) charge deposit account 502117 the petition fee set forth in §1.17(i).

VII. <u>Statement under 37 C.F.R. §1.97(e)</u> (check <u>only</u> one box, if applicable) The undersigned hereby states that

- a. each item of information contained in the IDS was cited in a communication from a foreign Patent Office is a counterpart foreign application not more than three months prior to the filing of IDS; or
- b. no item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application, and to knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement, or
- some of the items of information contained in the IDS were cited in a communication from a foreign Patent Office. As to this information, the undersigned states that each item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application not more than three months prior to the filing of this IDS. As to the remaining information, the undersigned hereby states that no item of this remaining information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application or, to the knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement.

VIII. PAYMENT OF FEES

	A check in the amount of is enclosed for the above-identified fee(s).
	Please charge Deposit Account No. 502117 in the amount of \$180.00 for the
	above-indicated fee(s).
\boxtimes	If Applicant has overlooked any additional fees, or if any overpayment has been
	made, the Commissioner is hereby authorized to credit or debit Deposit Account
	502117.
	Two Copies of this paper are attached for Deposit Account charges and debits.

The above references are being cited only in the interests of candor and without any admission that they constitute statutory prior art or contain matter which anticipates the invention or which would render the same obvious, either singly or in a combination, to a person of ordinary skill in the art.

If the Examiner has any questions concerning this IDS, he/she is requested to contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the PTO is requested to consider this IDS under the proper rule (with a petition if necessary) and charge the appropriate fee to Deposit Account No. 502117.

Respectfully submitted,

Leo Mathew et al.

Daniel D. Hill

Attorney for Applicant(s)

Reg. No. 35,895

Tel. (512) 996-6839

MOTOROLA, INC. Customer Number 23125

Enclosures:

☑ PTO/SB/08

References

Foreign Search Report

Other: Copy of related application 10/074,732

Substitute for form 1449A/PTO				Complete if Known			
				Application Number			
INFORM	IATION DISC	LOSURE		Filing Date			
STATEMENT BY APPLICANT				First Named Inventor	Leo Mathew		
• , , , , ,				Group Art Unit			
(use as many sheets as necessary)				Examiner Name			
Sheet	1	of	1	Attorney Docket Number	SC12862TC		

			U. S.	PATENT DOCUMENTS		
Examiner	Cite	U.S. Patent Document		Name of Patentee or	Date of	Pages, Columns, Lines, Where
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		Ohr, "F	inFETs and I	nP Ics Vie for	Multiple-Gate Transis	stors," IEEE, Spe re Ics," Silicon St	rategies, pp. 1-4 (2003	3).		
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ³ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁴ Applicant is to place a check mark here if English Language Translation is attached.